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	Application No.	Applicant(s)	
Nation of Allowahility	10/616,721	LEE, WON-HO	
Notice of Allowability	Examiner	Art Unit	
	Que T. Le	2878	
The MAILING DATE of this communication app All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT I of the Office or upon petition by the applicant. See 37 CFR 1.31	S (OR REMAINS) CLOSED in 5) or other appropriate commu RIGHTS. This application is s	this application. If not included inication will be mailed in due course. T	
1. This communication is responsive to			
2. The allowed claim(s) is/are <u>1-6</u> .			
3. \boxtimes The drawings filed on <u>10 July 2003</u> are accepted by the E	xaminer.		
 4. Acknowledgment is made of a claim for foreign priority of a) All b) Some* c) None of the: 1. Certified copies of the priority documents have 2. Certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have the certified copies of the priority documents have Copies of the certified copies of the priority documents have Tertified copies not received: 	ve been received. ve been received in Applicatio	n No	the
Applicant has THREE MONTHS FROM THE "MAILING DATE noted below. Failure to timely comply will result in ABANDON THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.	" of this communication to file MENT of this application.	a reply complying with the requirement	ts
5. A SUBSTITUTE OATH OR DECLARATION must be subi INFORMAL PATENT APPLICATION (PTO-152) which give)F
 CORRECTED DRAWINGS (as "replacement sheets") mution (a) including changes required by the Notice of Draftspe 1) hereto or 2) to Paper No./Mail Date (b) including changes required by the attached Examine Paper No./Mail Date (learning indicia such as the application number (see 37 CFR each sheet. Replacement sheet(s) should be labeled as such in 	rson's Patent Drawing Review r's Amendment / Comment or 1.84(c)) should be written on the	in the Office action of te drawings in the front (not the back) of	
7. DEPOSIT OF and/or INFORMATION about the dep attached Examiner's comment regarding REQUIREMENT	osit of BIOLOGICAL MATI	ERIAL must be submitted. Note the	
 Attachment(s) 1. Notice of References Cited (PTO-892) 2. Notice of Draftperson's Patent Drawing Review (PTO-948) 3. Information Disclosure Statements (PTO-1449 or PTO/SB Paper No./Mail Date	6. Interview S Paper No./ /08), 7. Examiner's	J a.	
		Que T. Le Primary Examiner	

The following is an examiner's statement of reasons for allowance: The prior art fails to teach a method for fabricating an image sensor having a device isolation layer with a trench structure and the sensor is integrated with a depletion mode transistor and a typical transistor comprising the steps of: forming sequentially a buffer oxide layer and a pad nitride layer on a substrate and patterning the both layers on a first region for the depletion mode transistor and a second region for the typical transistor by performing a device isolation mask process and an etch process to form trenches in both regions; forming a spacer at lateral sides of the trenches; masking the second region to form a high concentration of a first channel stop ion implantation region at a bottom side of the depletion mode transistor by using high energy; removing the spacer; masking the second region to form a low concentration of a second channel stop ion implantation region using low energy to encompass the lateral sides and the bottom side of the trench in the first region; and burying an insulation material into the trenches.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

I) Yang et al 6,184,055 disclose an image sensor structure having a depletion transistor.

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Que T. Le whose telephone number is (571) 272-2438.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David P. Porta, can be reached on (571) 272-2444. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

Que T. Le

Primary Examiner